# PE42443

# **Document Category: Product Brief**

# Semi A Murata Company

## UltraCMOS® SP4T RF Switch, 1.8 GHz-5 GHz

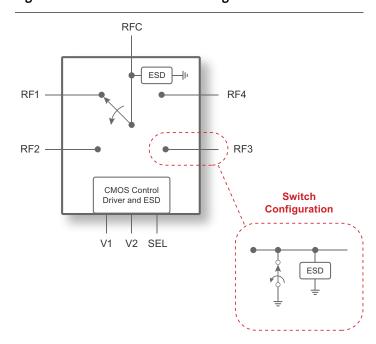
## **Features**

- · Low insertion loss:
  - 0.4 dB at 2.6 GHz typical
  - 0.49 dB at 3.8 GHz typical
- · High linearity IIP3: 85 dBm
- High power handling: 40 dBm RMS, 50 dBm peak
- 105°C operating temperature
- Packaging 20-lead 4 x 4 mm LGA

# **Applications**

- · Analog front end for hybrid beamforming
- 5G massive MIMO active antenna system (AAS)
- 4G/4.5G TD-LTE macro/micro cell/RRH

Figure 1 • PE42443 Functional Diagram



# **Product Description**

The PE42443 is a HaRP™ technology-enhanced SP4T RF switch that supports a frequency range from 1.8 GHz to 5 GHz. It delivers extremely low insertion loss, high linearity and fast switching time with high input power handling capability making this device ideal for hybrid beamforming and in 5G massive MIMO (Multi Input Multi Output) applications. No blocking capacitors are required if DC voltage is not present on the RF ports.

pSemi's HaRP™ technology enhancements deliver high linearity and excellent harmonics performance. It is an innovative feature of the UltraCMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

The PE42443 is manufactured on pSemi's UltraCMOS® process, a patented advanced form of silicon-on-insulator (SOI) technology.

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# **Ordering Information**

Table 1 lists the available ordering codes for the PE42443 as well as available shipping methods.

## Table 1 ■ Order Codes for PE42443

Order Codes	Description	Packaging	Shipping Method
PE42443A-Z	PE42443 SP4T switch	Green 20-lead 4 x 4 mm LGA	3000 units/T&R
EK42443-01	PE42443 evaluation kit	Evaluation kit	1/box

## **Document Categories**

## **Advance Information**

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

## Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. pSemi reserves the right to change specifications at any time without notice in order to supply the best possible product.

## **Product Specification**

The datasheet contains final data. In the event pSemi decides to change the specifications, pSemi will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

#### **Product Brief**

This document contains a shortened version of the datasheet. For the full datasheet, contact sales@psemi.com.

### Sales Contact

For additional information, contact Sales at sales@psemi.com.

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